

TOSHIBA Field-Effect Transistor Silicon N-Channel MOS Type

**SSM3K329R**

○ Power Management Switch Applications

○ High-Speed Switching Applications

Unit: mm

- 1.8-V drive
- Low ON-resistance:  $R_{DS(ON)} = 289 \text{ m}\Omega$  (max) (@ $V_{GS} = 1.8 \text{ V}$ )  
:  $R_{DS(ON)} = 170 \text{ m}\Omega$  (max) (@ $V_{GS} = 2.5 \text{ V}$ )  
:  $R_{DS(ON)} = 126 \text{ m}\Omega$  (max) (@ $V_{GS} = 4.0 \text{ V}$ )

**Absolute Maximum Ratings (Ta = 25°C)**

Characteristic	Symbol	Rating	Unit
Drain-source voltage	$V_{DSS}$	30	V
Gate-source voltage	$V_{GSS}$	$\pm 12$	V
Drain current	DC $I_D$ (Note 1)	3.5	A
	Pulse $I_{DP}$ (Note 1)	7.0	
Power dissipation	$P_D$ (Note 2)	1	W
	$t = 10\text{s}$	2	
Channel temperature	$T_{ch}$	150	°C
Storage temperature range	$T_{stg}$	-55 to 150	°C

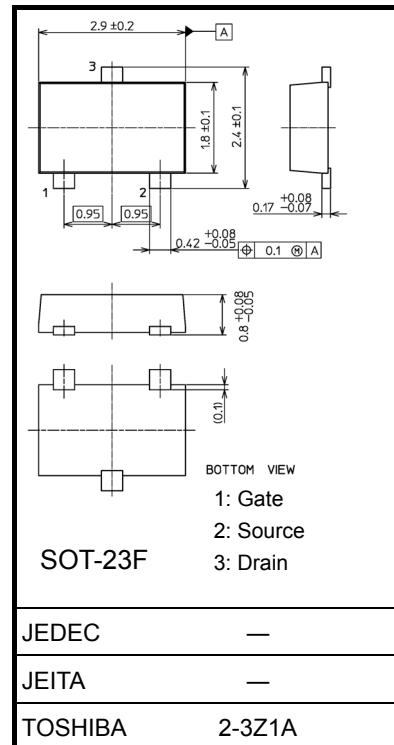
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Note 1: The channel temperature should not exceed 150°C during use.

Note 2: Mounted on a FR4 board.

(25.4 mm × 25.4 mm × 1.6 mm, Cu Pad: 645 mm<sup>2</sup>)



Weight: 11 mg (typ.)

**Handling Precaution**

When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

Thermal resistance  $R_{th(ch-a)}$  and Power dissipation  $P_D$  vary depending on board material, board area, board thickness and pad area. When using this device, please take heat dissipation into consideration

Start of commercial production  
2010-02

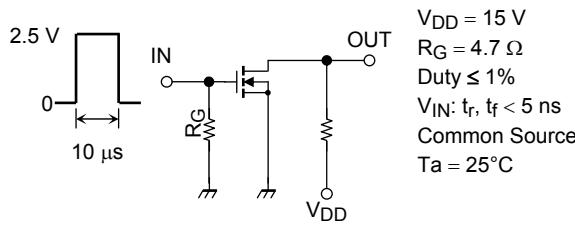
## Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Conditions	Min	Typ.	Max	Unit
Drain-source breakdown voltage	V (BR) DSS	Id = 1 mA, VGS = 0 V	30	—	—	V
	V (BR) DSX	Id = 1 mA, VGS = -12 V	18	—	—	
Drain cut-off current	IdSS	VDS = 30 V, VGS = 0 V	—	—	1	μA
Gate leakage current	IGSS	VGS = ± 12 V, VDS = 0 V	—	—	±1	μA
Gate threshold voltage	Vth	VDS = 3 V, Id = 1 mA	0.4	—	1.0	V
Forward transfer admittance	Yfs	VDS = 3 V, Id = 1.0 A (Note 3)	2.1	4.2	—	S
Drain-source ON-resistance	RDS (ON)	Id = 1.0 A, VGS = 4.0 V (Note 3)	—	96	126	mΩ
		Id = 0.8 A, VGS = 2.5 V (Note 3)	—	118	170	
		Id = 0.5 A, VGS = 1.8 V (Note 3)	—	158	289	
Input capacitance	Ciss	VDS = 15V, VGS = 0 V, f = 1 MHz	—	123	—	pF
Output capacitance	Coss		—	43	—	
Reverse transfer capacitance	Crss		—	18	—	
Total gate charge	Qg	VDS = 15V, Id = 2.0 A VGS = 4 V	—	1.5	—	nC
Gate-source charge	Qgs1		—	0.3	—	
Gate-drain charge	Qgd		—	0.6	—	
Switching time	Turn-on time	t <sub>on</sub>	VDD = 15 V, Id = 1.0 A, VGS = 0 to 2.5 V, RG = 4.7 Ω	—	9.2	ns
	Turn-off time	t <sub>off</sub>		—	6.4	
Drain-source forward voltage	V <sub>DSF</sub>	Id = -3.5 A, VGS = 0 V (Note 3)	—	-0.90	-1.2	V

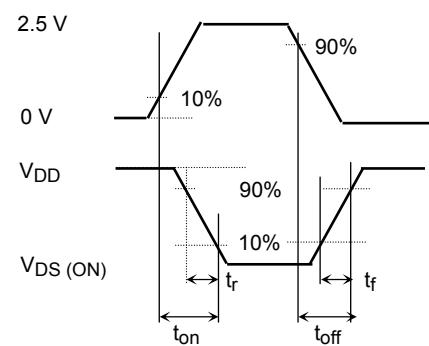
Note 3: Pulse test

## Switching Time Test Circuit

(a) Test Circuit

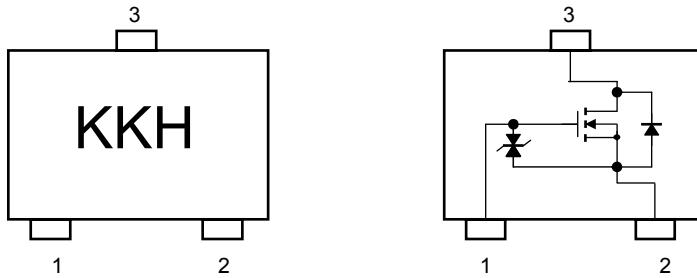


$V_{DD} = 15 \text{ V}$   
 $R_G = 4.7 \Omega$   
Duty  $\leq 1\%$   
 $V_{IN}: t_r, t_f < 5 \text{ ns}$   
Common Source  
 $T_a = 25^\circ\text{C}$

(b)  $V_{IN}$ (c)  $V_{OUT}$ 

## Marking

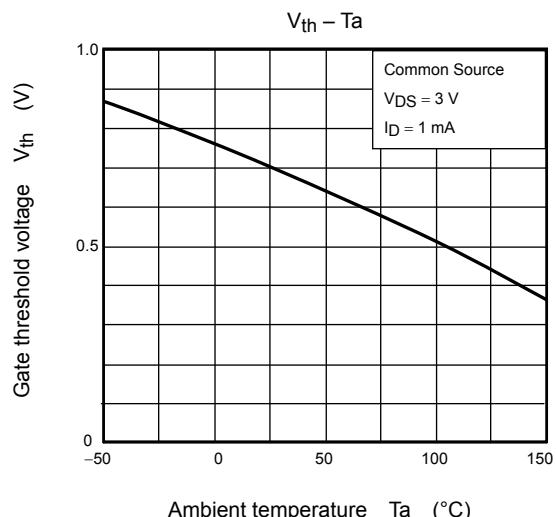
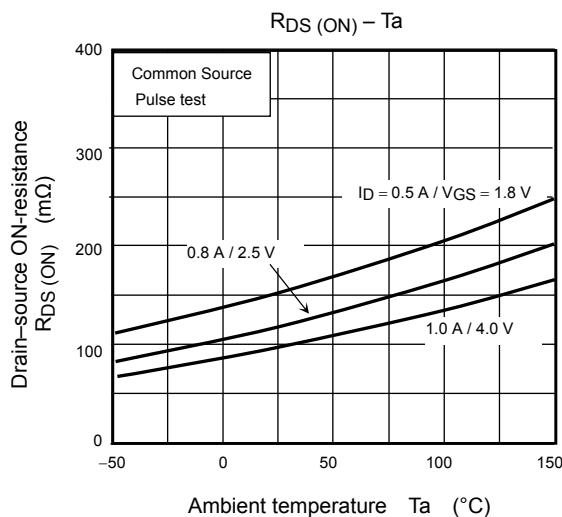
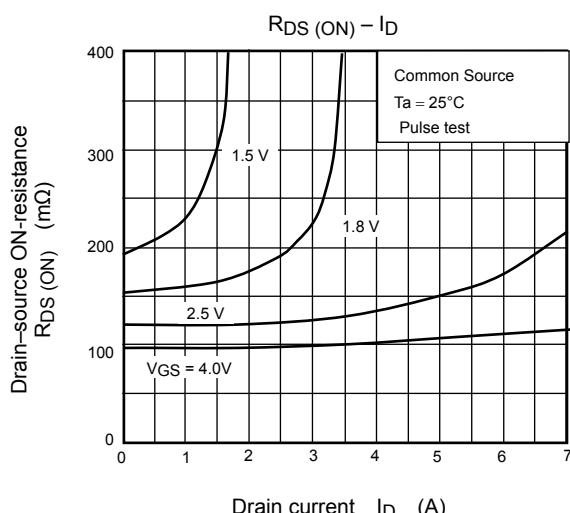
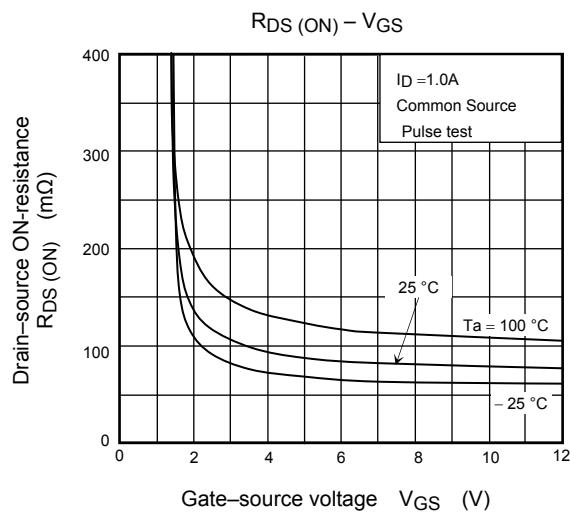
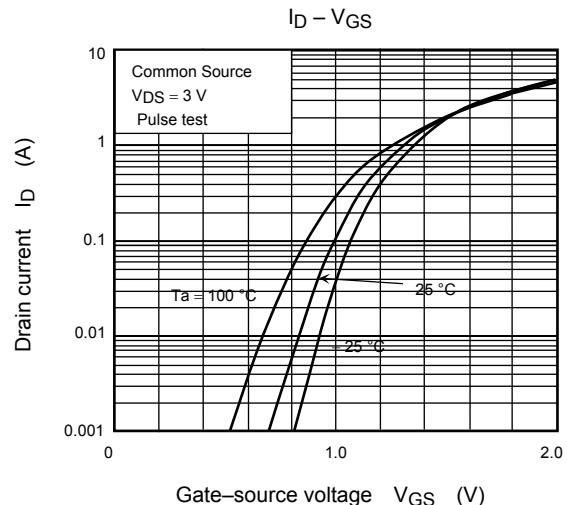
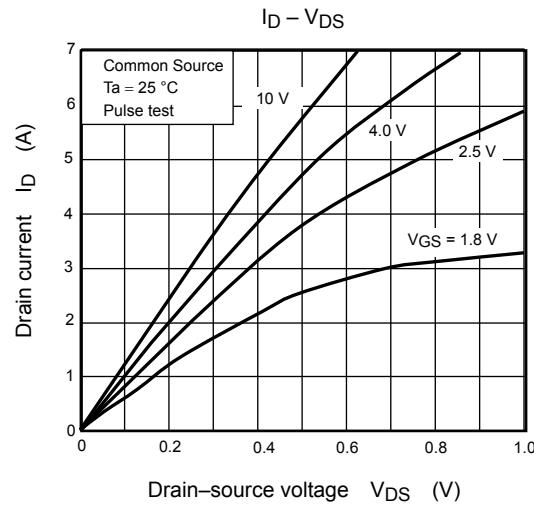
## Equivalent Circuit (top view)

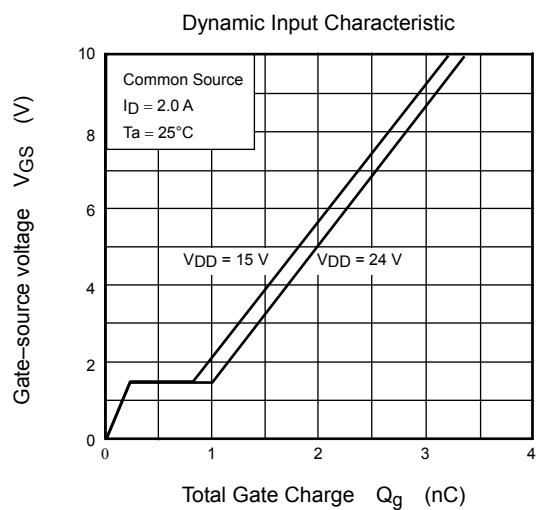
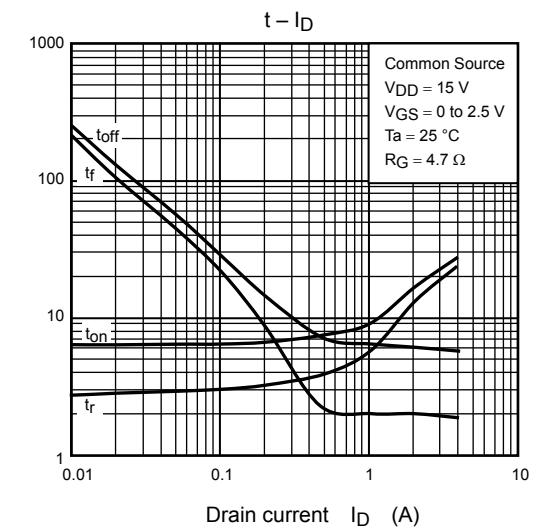
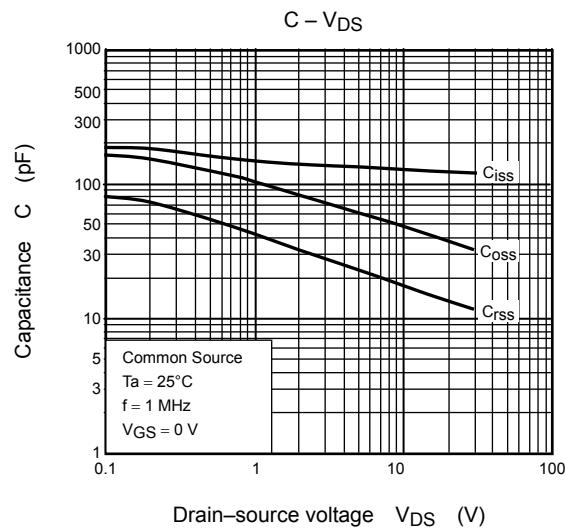
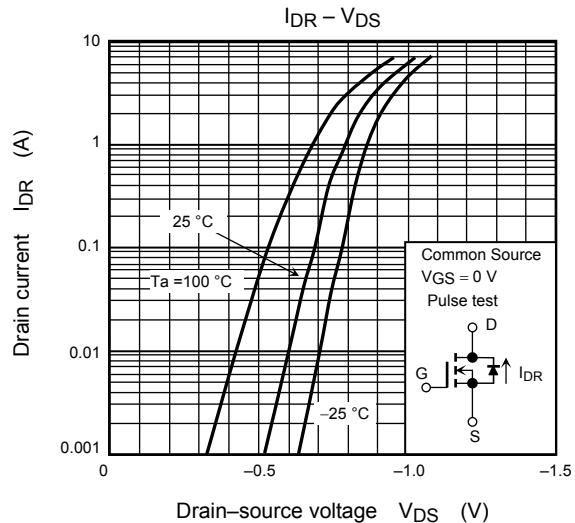
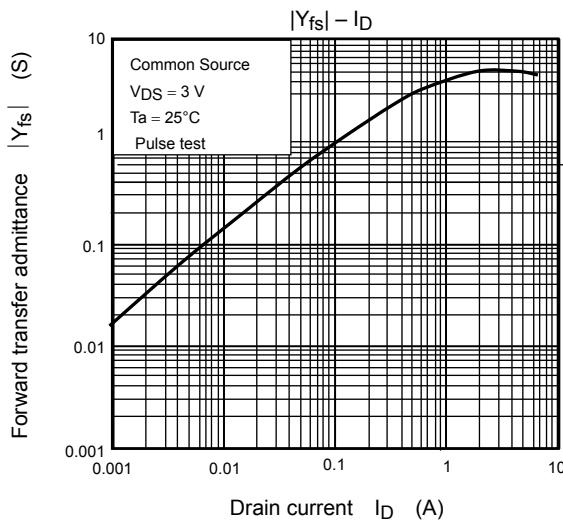


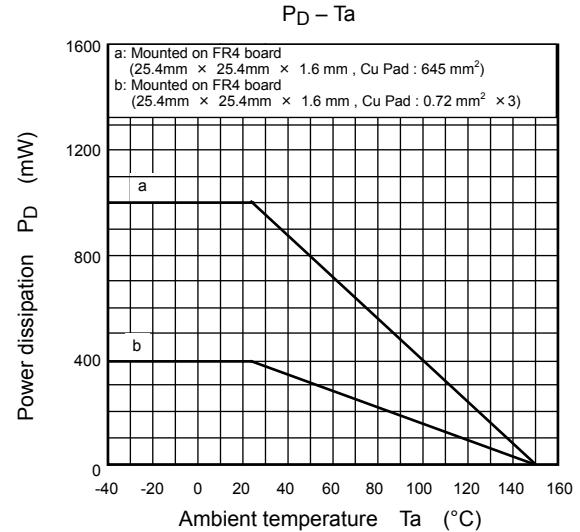
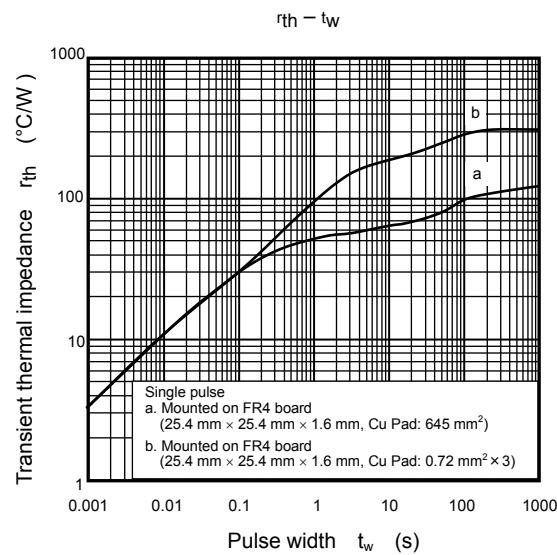
## Usage Considerations

Let  $V_{th}$  be the voltage applied between gate and source that causes the drain current ( $I_D$ ) to below (1 mA for the SSM3K329R). Then, for normal switching operation,  $V_{GS(on)}$  must be higher than  $V_{th}$ , and  $V_{GS(off)}$  must be lower than  $V_{th}$ . This relationship can be expressed as:  $V_{GS(off)} < V_{th} < V_{GS(on)}$ .

Take this into consideration when using the device.







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